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In the Claims:

- 1. (Currently Amended) A capacitor-reform method comprising:
 - a) charging at least one wet-tantalum capacitor in an implantable medical device;
 - b) allowing the one wet-tantalum capacitors to discharge through system leakage after charging the one wet-tantalum capacitor in the implantable medical device; and
 - c) discharging the one or more of the wet-tantalum capacitors through a non-therapeutic load, after allowing the one or more wet-tantalum capacitors to discharge through system leakage.
- (Original) The method of claim 1, wherein the implantable medical device has a housing and the nontherapeutic load is a resistor within the housing.
- 3. (Original) The method of claim 1, wherein the one wet-tantalum capacitor comprises a tantalum anode and a non-tantalum cathode.
- 4. (Original) The method of claim 1, wherein the implantable device includes means for defibrillation, means for cardioversion, or means for pacemaking.
- 5. (Currently Amended) A capacitor-reform method comprising:
 - a) charging at least one wet-tantalum capacitor to a high voltage relative its rated voltage or maximumenergy voltage;

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- <u>b)</u> partially discharging the one the wet-tantalum capacitors through system leakage after charging the one wet-tantalum capacitor to the high voltage; and
- c) discharging the one or more of the wet-tantalum capacitors through a non-therapeutic load, after partially discharging the one or more wet-tantalum capacitors through system leakage.
- 6. (Original) The method of claim 5, wherein the high voltage is about 90 percent of the rated voltage or a maximum-energy voltage for the capacitor.
- 7. (Original) The method of claim 5, wherein the implantable medical device has a housing and the non-therapeutic load is a resistor within the housing.
- 8. (Original) The method of claim 5, wherein the one wet-tantalum capacitor comprises a tantalum anode and a non-tantalum cathode.
- 9. (Original) The method of claim 5, wherein the partial discharging is initiated after a time period of at least 60 seconds.
- 10. (Original) The method of claim 5, wherein the implantable device includes means for defibrillation, means for cardioversion, or means for pacemaking.

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- (Currently Amended) A capacitor-reform method comprising: 11.
 - a) charging at least one wet-tantalum capacitor in an implantable medical device, in response to a reform signal from a processor in the medical device;
 - b) allowing the one wet-tantalum capacitors to discharge through system leakage after charging the one wet-tantalum capacitor in the implantable medical device; and
 - discharging the one or more of the wet-tantalum c) capacitors through a non-therapeutic load, after allowing the one or more wet-tantalum capacitors to discharge through system leakage.
- 12. (Original) The method of claim 11, wherein the implantable medical device has a housing and the nontherapeutic load is a resistor within the housing.
- 13. (Original) The method of claim 11, wherein the one wet-tantalum capacitor comprises a tantalum anode and a non-tantalum cathode.
- 14. (Original) The method of claim 11, wherein the implantable device includes means for defibrillation, means for cardioversion, or means for pacemaking.

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- 15. (Currently Amended) A capacitor-reform method comprising:
 - a) charging at least one wet-tantalum capacitor in a device to a voltage;
 - b) allowing the one wet-tantalum capacitors to discharge through system leakage after charging the one wet-tantalum capacitor in the device; and
 - c) discharging the one or more of the wet-tantalum capacitors through a load, after allowing the one or more wet-tantalum capacitors to discharge through system leakage.
- 16. (Original) The method of claim 15, wherein the device has a housing and the load is a resistor within the housing.
- 17. (Original) The method of claim 15, wherein the one wet-tantalum capacitor comprises a tantalum anode and a non-tantalum cathode.
- 18. (Original) The method of claim 15, wherein the device is implantable and includes a housing and at least one of means for defibrillation, means for cardioversion, and means for pacemaking; and wherein the load includes a resistor within the housing